

4-Kbit (512 × 8) Serial (I²C) Automotive-A F-RAM

Features

- 4-Kbit ferroelectric random access memory (F-RAM) logically organized as 512 × 8
 - High-endurance 100 trillion (10¹⁴) read/writes
 - 151-year data retention (See the [Data Retention and Endurance](#) table)
 - NoDelay™ writes
 - Advanced high-reliability ferroelectric process
- Fast two-wire Serial interface (I²C)
 - Up to 1-MHz frequency
 - Direct hardware replacement for serial (I²C) EEPROM
 - Supports legacy timings for 100 kHz and 400 kHz
- Low power consumption
 - 100 μA active current at 100 kHz
 - 4 μA (typ) standby current
- Voltage operation: V_{DD} = 4.5 V to 5.5 V
- Automotive-A temperature: –40 °C to +85 °C
- 8-pin small outline integrated circuit (SOIC) package
- Restriction of hazardous substances (RoHS) compliant

Functional Description

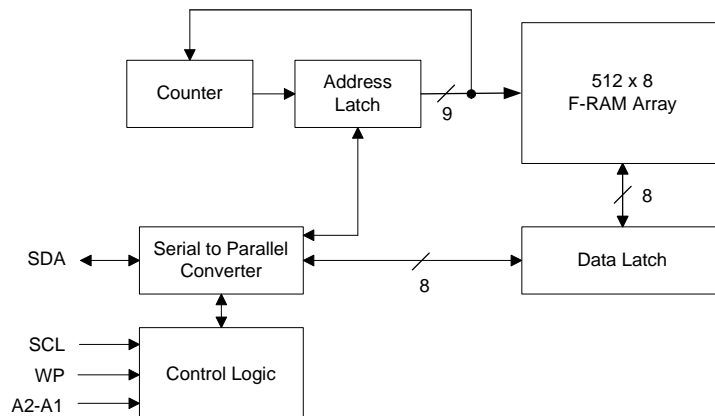
The CY15E004J is a 4-Kbit nonvolatile memory employing an advanced ferroelectric process. A ferroelectric random access memory or F-RAM is nonvolatile and performs reads and writes similar to a RAM. It provides reliable data retention for 151 years while eliminating the complexities, overhead, and system-level reliability problems caused by EEPROM and other nonvolatile memories.

Unlike EEPROM, the CY15E004J performs write operations at bus speed. No write delays are incurred. Data is written to the memory array immediately after each byte is successfully transferred to the device. The next bus cycle can commence without the need for data polling. In addition, the product offers substantial write endurance compared with other nonvolatile memories. Also, F-RAM exhibits much lower power during writes than EEPROM since write operations do not require an internally elevated power supply voltage for write circuits. The CY15E004J is capable of supporting 10¹⁴ read/write cycles, or 100 million times more write cycles than EEPROM.

These capabilities make the CY15E004J ideal for nonvolatile memory applications, requiring frequent or rapid writes. Examples range from data logging, where the number of write cycles may be critical, to demanding industrial controls where the long write time of EEPROM can cause data loss. The combination of features allows more frequent data writing with less overhead for the system.

The CY15E004J provides substantial benefits to users of serial (I²C) EEPROM as a hardware drop-in replacement. The device specifications are guaranteed over an automotive-a temperature range of –40 °C to +85 °C.

Logic Block Diagram

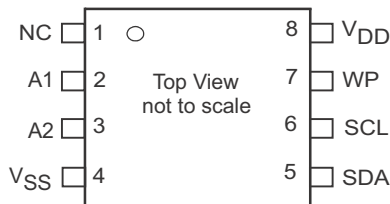


Contents

Pinout	3	Capacitance	10
Pin Definitions	3	Thermal Resistance	10
Functional Overview	4	AC Test Loads and Waveforms	10
Memory Architecture	4	AC Test Conditions	10
I2C Interface	4	AC Switching Characteristics	11
STOP Condition (P)	4	Power Cycle Timing	12
START Condition (S)	4	Ordering Information	13
Data/Address Transfer	5	Ordering Code Definitions	13
Acknowledge/No-acknowledge	5	Package Diagram	14
Slave Device Address	6	Acronyms	15
Addressing Overview (Word Address)	6	Document Conventions	15
Data Transfer	6	Units of Measure	15
Memory Operation	6	Document History Page	16
Write Operation	6	Sales, Solutions, and Legal Information	17
Read Operation	7	Worldwide Sales and Design Support	17
Endurance	8	Products	17
Maximum Ratings	9	PSoC® Solutions	17
Operating Range	9	Cypress Developer Community	17
DC Electrical Characteristics	9	Technical Support	17
Data Retention and Endurance	10		

Pinout

Figure 1. 8-pin SOIC pinout



Pin Definitions

Pin Name	I/O Type	Description
A2–A1	Input	Device Select Address 2–1. These pins are used to select one of up to 4 devices of the same type on the same I ² C bus. To select the device, the address value on the three pins must match the corresponding bits contained in the slave address. The address pins are pulled down internally.
SDA	Input/Output	Serial Data/Address. This is a bi-directional pin for the I ² C interface. It is open-drain and is intended to be wire-AND'd with other devices on the I ² C bus. The input buffer incorporates a Schmitt trigger for noise immunity and the output driver includes slope control for falling edges. An external pull-up resistor is required.
SCL	Input	Serial Clock. The serial clock pin for the I ² C interface. Data is clocked out of the device on the falling edge, and into the device on the rising edge. The SCL input also incorporates a Schmitt trigger input for noise immunity.
WP	Input	Write Protect. When tied to V _{DD} , addresses in the entire memory map will be write-protected. When WP is connected to ground, all addresses are write enabled. This pin is pulled down internally.
V _{SS}	Power supply	Ground for the device. Must be connected to the ground of the system.
V _{DD}	Power supply	Power supply input to the device.
NC	NC	No Connect. Die pads are not connected to the package pin.

Functional Overview

The CY15E004J is a serial F-RAM memory. The memory array is logically organized as 512 × 8 bits and is accessed using an industry-standard I²C interface. The functional operation of the F-RAM is similar to serial (I²C) EEPROM. The major difference between the CY15E004J and a serial (I²C) EEPROM with the same pinout is the F-RAM's superior write performance, high endurance, and low power consumption.

Memory Architecture

When accessing the CY15E004J, the user addresses 512 locations of eight data bits each. These eight data bits are shifted in or out serially. The addresses are accessed using the I²C protocol, which includes a slave address (to distinguish other non-memory devices), a page address bit, and a word address. The word address consists of 8-bits that specify one of the 256 addresses. The page address is 1-bit and so there are 2 pages of 256 locations. The complete address of 9-bits specifies each byte address uniquely.

The access time for the memory operation is essentially zero, beyond the time needed for the serial protocol. That is, the memory is read or written at the speed of the I²C bus. Unlike a serial (I²C) EEPROM, it is not necessary to poll the device for a ready condition because writes occur at bus speed. By the time a new bus transaction can be shifted into the device, a write

operation is complete. This is explained in more detail in the interface section.

Note that the CY15E004J contains no power management circuits other than a simple internal power-on reset. It is the user's responsibility to ensure that V_{DD} is within data sheet tolerances to prevent incorrect operation.

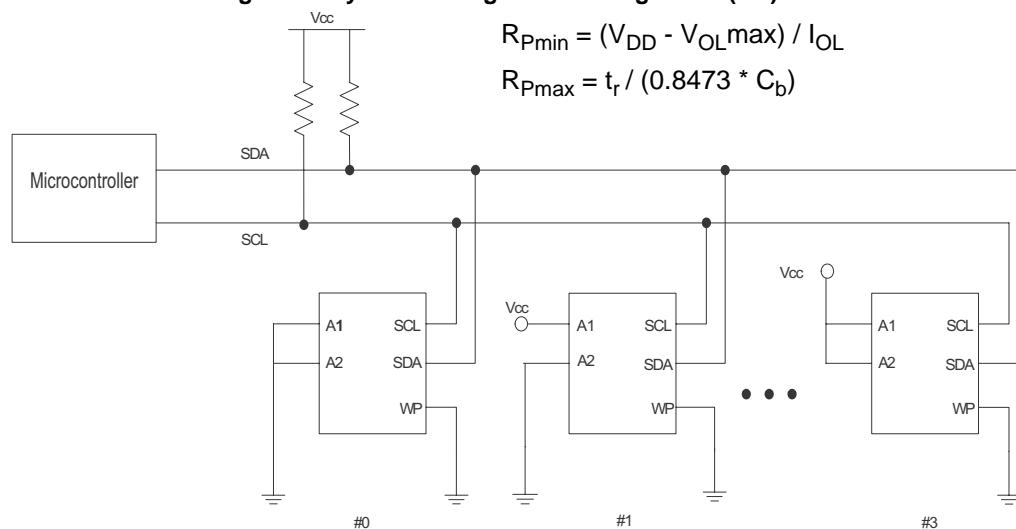
I²C Interface

The CY15E004J employs a bi-directional I²C bus protocol using few pins or board space. [Figure 2](#) illustrates a typical system configuration using the CY15E004J in a microcontroller-based system. The industry standard I²C bus is familiar to many users but is described in this section.

By convention, any device that is sending data onto the bus is the transmitter while the target device for this data is the receiver. The device that is controlling the bus is the master. The master is responsible for generating the clock signal for all operations. Any device on the bus that is being controlled is a slave. The CY15E004J is always a slave device.

The bus protocol is controlled by transition states in the SDA and SCL signals. There are four conditions including START, STOP, data bit, or acknowledge. [Figure 3 on page 5](#) and [Figure 4 on page 5](#) illustrates the signal conditions that specify the four states. Detailed timing diagrams are shown in the electrical specifications section.

Figure 2. System Configuration using Serial (I²C) nvSRAM



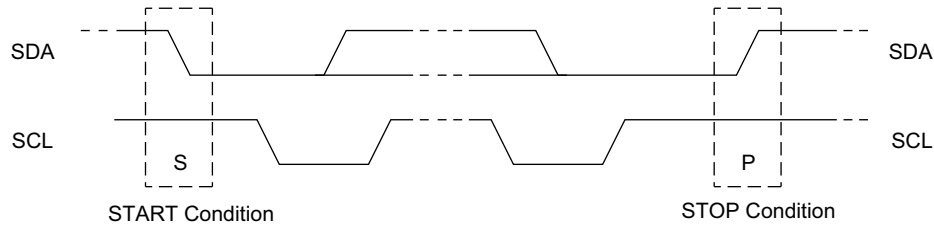
STOP Condition (P)

A STOP condition is indicated when the bus master drives SDA from LOW to HIGH while the SCL signal is HIGH. All operations using the CY15E004J should end with a STOP condition. If an operation is in progress when a STOP is asserted, the operation will be aborted. The master must have control of SDA in order to assert a STOP condition.

START Condition (S)

A START condition is indicated when the bus master drives SDA from HIGH to LOW while the SCL signal is HIGH. All commands should be preceded by a START condition. An operation in progress can be aborted by asserting a START condition at any time. Aborting an operation using the START condition will ready the CY15E004J for a new operation.

If during operation the power supply drops below the specified V_{DD} minimum, the system should issue a START condition prior to performing another operation.

Figure 3. START and STOP Conditions

Figure 4. Data Transfer on the I²C Bus


Data/Address Transfer

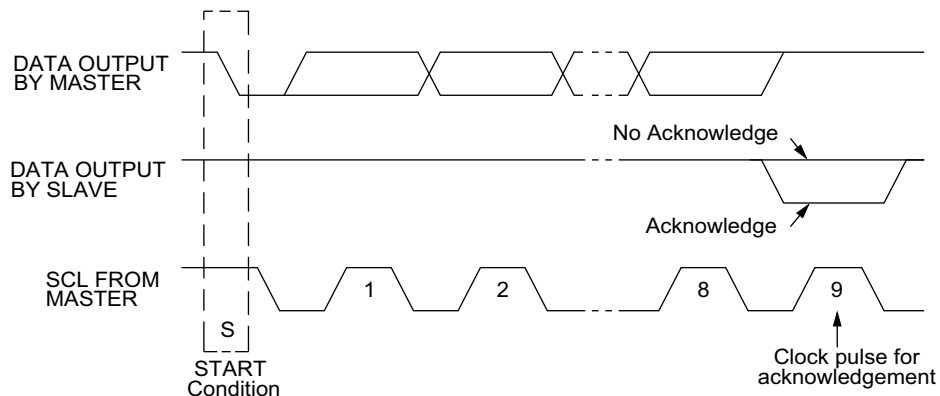
All data transfers (including addresses) take place while the SCL signal is HIGH. Except under the three conditions described above, the SDA signal should not change while SCL is HIGH.

Acknowledge/No-acknowledge

The acknowledge takes place after the 8th data bit has been transferred in any transaction. During this state the transmitter should release the SDA bus to allow the receiver to drive it. The receiver drives the SDA signal LOW to acknowledge receipt of the byte. If the receiver does not drive SDA LOW, the condition is a no-acknowledge and the operation is aborted.

The receiver would fail to acknowledge for two distinct reasons. First is that a byte transfer fails. In this case, the no-acknowledge ceases the current operation so that the device can be addressed again. This allows the last byte to be recovered in the event of a communication error.

Second and most common, the receiver does not acknowledge to deliberately end an operation. For example, during a read operation, the CY15E004J will continue to place data onto the bus as long as the receiver sends acknowledges (and clocks). When a read operation is complete and no more data is needed, the receiver must not acknowledge the last byte. If the receiver acknowledges the last byte, this will cause the CY15E004J to attempt to drive the bus on the next clock while the master is sending a new command such as STOP.

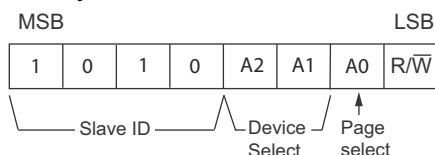
Figure 5. Acknowledge on the I²C Bus


Slave Device Address

The first byte that the CY15E004J expects after a START condition is the slave address. As shown in Figure 6, the slave address contains the device type or slave ID, the device select address bits, a page select bit, and a bit that specifies if the transaction is a read or a write.

Bits 7-4 are the device type (slave ID) and should be set to 1010b for the CY15E004J. These bits allow other function types to reside on the I²C bus within an identical address range. Bits 3-2 are the device select address bits. They must match the corresponding value on the external address pins to select the device. Up to four CY15E004J devices can reside on the same I²C bus by assigning a different address to each. Bit 1 is the page select bit. It specifies the 256-byte block of memory that is targeted for the current operation. Bit 0 is the read/write bit (R/W). R/W = '1' indicates a read operation and R/W = '0' indicates a write operation.

Figure 6. Memory Slave Device Address



Addressing Overview (Word Address)

After the CY15E004J (as receiver) acknowledges the slave address, the master can place the word address on the bus for a write operation. The word address is the lower 8-bits of the address to be combined with the 1-bit page select to specify exactly the byte to be written. The complete 9-bit address is latched internally. No word address occurs for a read operation. Reads always use the lower 8-bits that are held internally in the address latch and the 9th address bit is part of the slave address. Reads always begin at the address following the previous access. A random read address can be loaded by doing a write operation as explained below.

After transmission of each data byte, just prior to the acknowledge, the CY15E004J increments the internal address latch. This allows the next sequential byte to be accessed with no additional addressing. After the last address (1FFh) is reached, the address latch will roll over to 000h. There is no limit to the number of bytes that can be accessed with a single read or write operation.

Data Transfer

After the address bytes have been transmitted, data transfer between the bus master and the CY15E004J can begin. For a read operation the CY15E004J will place 8 data bits on the bus

then wait for an acknowledge from the master. If the acknowledge occurs, the CY15E004J will transfer the next sequential byte. If the acknowledge is not sent, the CY15E004J will end the read operation. For a write operation, the CY15E004J will accept 8 data bits from the master then send an acknowledge. All data transfer occurs MSB (most significant bit) first.

Memory Operation

The CY15E004J is designed to operate in a manner very similar to other I²C interface memory products. The major differences result from the higher performance write capability of F-RAM technology. These improvements result in some differences between the CY15E004J and a similar configuration EEPROM during writes. The complete operation for both writes and reads is explained below.

Write Operation

All writes begin with a slave address, then a word address. The bus master indicates a write operation by setting the LSB of the slave address (R/W bit) to a '0'. After addressing, the bus master sends each byte of data to the memory and the memory generates an acknowledge condition. Any number of sequential bytes may be written. If the end of the address range is reached internally, the address counter will wrap from 1FFh to 000h.

Unlike other nonvolatile memory technologies, there is no effective write delay with F-RAM. Since the read and write access times of the underlying memory are the same, the user experiences no delay through the bus. The entire memory cycle occurs in less time than a single bus clock. Therefore, any operation including read or write can occur immediately following a write. Acknowledge polling, a technique used with EEPROMs to determine if a write is complete is unnecessary and will always return a ready condition.

Internally, an actual memory write occurs after the 8th data bit is transferred. It will be complete before the acknowledge is sent. Therefore, if the user desires to abort a write without altering the memory contents, this should be done using START or STOP condition prior to the 8th data bit. The CY15E004J uses no page buffering.

The memory array can be write-protected using the WP pin. Setting the WP pin to a HIGH condition (V_{DD}) will write-protect all addresses. The CY15E004J will not acknowledge data bytes that are written to protected addresses. In addition, the address counter will not increment if writes are attempted to these addresses. Setting WP to a LOW state (V_{SS}) will disable the write protect. WP is pulled down internally.

Figure 7 and Figure 8 on page 7 below illustrate a single-byte and multiple-byte write cycles.

Figure 7. Single-Byte Write

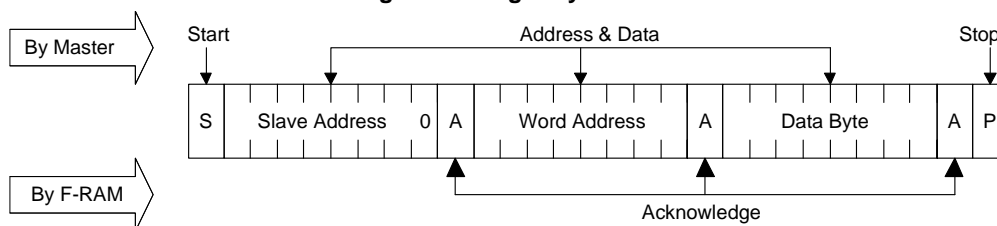
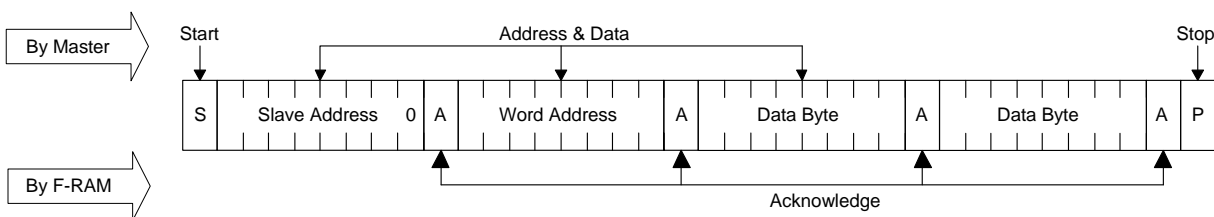


Figure 8. Multi-Byte Write


Read Operation

There are two basic types of read operations. They are current address read and selective address read. In a current address read, the CY15E004J uses the internal address latch to supply the lower 8 address bits. In a selective read, the user performs a procedure to set these lower address bits to a specific value.

Current Address & Sequential Read

As mentioned above the CY15E004J uses an internal latch to supply the lower 8 address bits for a read operation. A current address read uses the existing value in the address latch as a starting place for the read operation. The system reads from the address immediately following that of the last operation.

To perform a current address read, the bus master supplies a slave address with the LSB set to a '1'. This indicates that a read operation is requested. The page select bit in the slave address specifies the block of memory that is used for the read operation. After receiving the complete slave address, the CY15E004J will begin shifting out data from the current address on the next clock. The current address is the bit from the slave address combined with the 8-bits that were in the internal address latch.

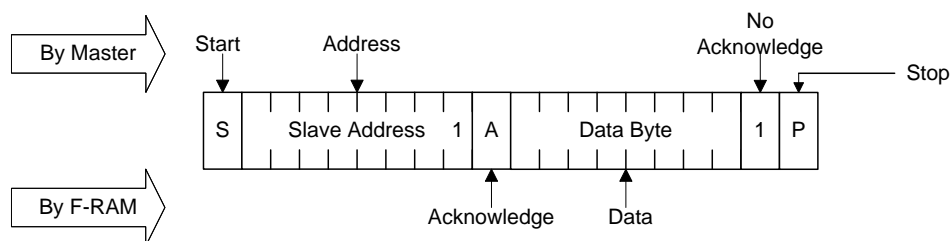
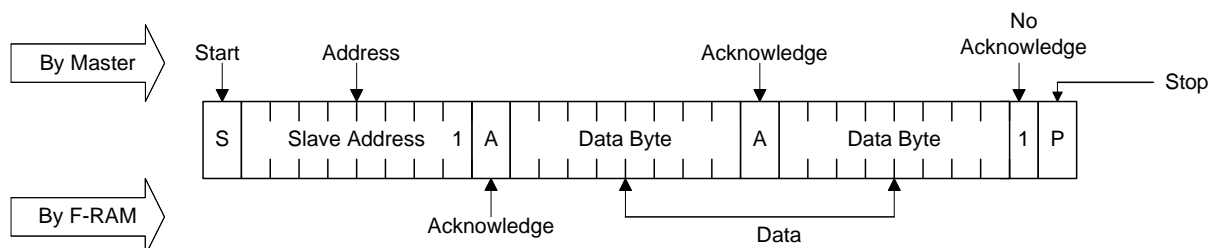
Beginning with the current address, the bus master can read any number of bytes. Thus, a sequential read is simply a current address read with multiple byte transfers. After each byte the internal address counter will be incremented.

Note Each time the bus master acknowledges a byte, this indicates that the CY15E004J should read out the next sequential byte.

There are four ways to properly terminate a read operation. Failing to properly terminate the read will most likely create a bus contention as the CY15E004J attempts to read out additional data onto the bus. The four valid methods are:

1. The bus master issues a no-acknowledge in the 9th clock cycle and a STOP in the 10th clock cycle. This is illustrated in the diagrams below. This is preferred.
2. The bus master issues a no-acknowledge in the 9th clock cycle and a START in the 10th.
3. The bus master issues a STOP in the 9th clock cycle.
4. The bus master issues a START in the 9th clock cycle.

If the internal address reaches 1FFh, it will wrap around to 000h on the next read cycle. [Figure 9](#) and [Figure 10](#) below show the proper operation for current address reads.

Figure 9. Current Address Read

Figure 10. Sequential Read


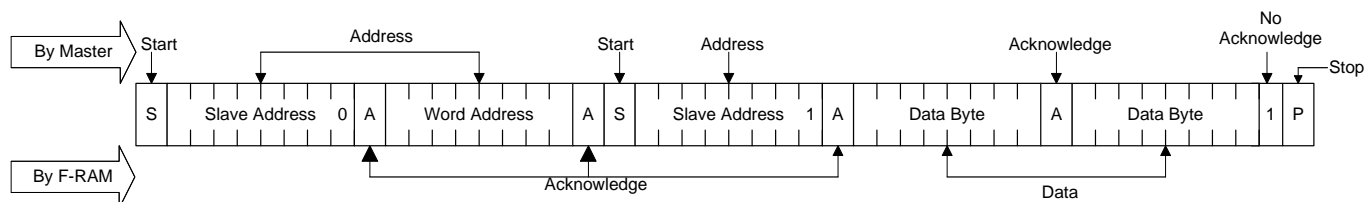
Selective (Random) Read

There is a simple technique that allows a user to select a random address location as the starting point for a read operation. This involves using the first two bytes of a write operation to set the internal address followed by subsequent read operations.

To perform a selective read, the bus master sends out the slave address with the LSB (R/W) set to 0. This specifies a write

operation. According to the write protocol, the bus master then sends the word address byte that is loaded into the internal address latch. After the CY15E004J acknowledges the word address, the bus master issues a START condition. This simultaneously aborts the write operation and allows the read command to be issued with the slave address LSB set to a '1'. The operation is now a current address read.

Figure 11. Selective (Random) Read



Endurance

The CY15E004J internally operates with a read and restore mechanism. Therefore, endurance cycles are applied for each read or write cycle. The memory architecture is based on an array of rows and columns. Each read or write access causes an endurance cycle for an entire row. In the CY15E004J, a row is

64 bits wide. Every 8-byte boundary marks the beginning of a new row. Endurance can be optimized by ensuring frequently accessed data is located in different rows. Regardless, F-RAM read and write endurance is effectively unlimited at the 1-MHz I²C speed. Even at 3000 accesses per second to the same row, 10 years time will elapse before 1 trillion endurance cycles occur.

Maximum Ratings

Exceeding maximum ratings may shorten the useful life of the device. These user guidelines are not tested.

Storage temperature -55 °C to +125 °C

Maximum accumulated storage time

At 125 °C ambient temperature 1000 h

At 85 °C ambient temperature 10 Years

Ambient temperature

with power applied -55 °C to +125 °C

Supply voltage on V_{DD} relative to V_{SS} -1.0 V to +7.0 V

Input voltage -1.0 V to +7.0 V and $V_{IN} < V_{DD} + 1.0$ V

DC voltage applied to outputs

in High-Z state -0.5 V to $V_{DD} + 0.5$ V

Transient voltage (< 20 ns)

on any pin to ground potential -2.0 V to $V_{DD} + 2.0$ V

Package power

dissipation capability ($T_A = 25$ °C) 1.0 W

Surface mount lead

soldering temperature (10 seconds) +260 °C

Electrostatic Discharge Voltage ^[1]

Human Body Model (AEC-Q100-002 Rev. E) 2 kV

Charged Device Model (AEC-Q100-011 Rev. B) 500 V

Latch-up current > 140 mA

* Exception: The " $V_{IN} < V_{DD} + 1.0$ V" restriction does not apply to the SCL and SDA inputs.

Operating Range

Range	Ambient Temperature (T_A)	V_{DD}
Automotive-A	-40 °C to +85 °C	4.5 V to 5.5 V

DC Electrical Characteristics

Over the [Operating Range](#)

Parameter	Description	Test Conditions	Min	Typ ^[2]	Max	Unit
V_{DD}	Power supply		4.5	5.0	5.5	V
I_{DD}	Average V_{DD} current	SCL toggling between $V_{DD} - 0.3$ V and V_{SS} , other inputs V_{SS} or $V_{DD} - 0.3$ V.	$f_{SCL} = 100$ kHz	—	—	100 μ A
			$f_{SCL} = 400$ kHz	—	—	200 μ A
			$f_{SCL} = 1$ MHz	—	—	400 μ A
I_{SB}	Standby current	SCL = SDA = V_{DD} . All other inputs V_{SS} or V_{DD} . Stop command issued.	—	4	10	μ A
I_{LI}	Input leakage current (Except WP and A2–A1)	$V_{SS} \leq V_{IN} \leq V_{DD}$	–1	—	+1	μ A
	Input leakage current (for WP and A2–A1)	$V_{SS} \leq V_{IN} \leq V_{DD}$	–1	—	+100	μ A
I_{LO}	Output leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	–1	—	+1	μ A
V_{IH}	Input HIGH voltage		$0.7 \times V_{DD}$	—	$V_{DD} + 0.3$	V
V_{IL}	Input LOW voltage		–0.3	—	$0.3 \times V_{DD}$	V
V_{OL}	Output LOW voltage	$I_{OL} = 3$ mA	—	—	0.4	V
$R_{in}^{[3]}$	Input resistance (WP, A2–A1)	For $V_{IN} = V_{IL}$ (Max)	40	—	—	k Ω
		For $V_{IN} = V_{IH}$ (Min)	1	—	—	M Ω
$V_{HYS}^{[4]}$	Input Hysteresis		$0.05 \times V_{DD}$	—	—	V

Notes

- Electrostatic Discharge voltages specified in the datasheet are the AEC-Q100 standard limits used for qualifying the device. To know the maximum value device passes for, please refer to the [device qualification report](#) available on the website.
- Typical values are at 25 °C, $V_{DD} = V_{DD}$ (typ). Not 100% tested.
- The input pull-down circuit is strong (40 k Ω) when the input voltage is below V_{IL} and weak (1 M Ω) when the input voltage is above V_{IH} .
- These parameters are guaranteed by design and are not tested.

Data Retention and Endurance

Parameter	Description	Test condition	Min	Max	Unit
T _{DR}	Data retention	T _A = 85 °C	10	–	Years
		T _A = 75 °C	38	–	
		T _A = 65 °C	151	–	
NV _C	Endurance	Over operating temperature	10 ¹⁴	–	Cycles

Capacitance

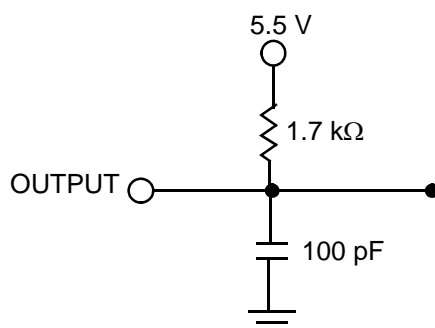
Parameter ^[5]	Description	Test Conditions	Max	Unit
C _O	Output pin capacitance (SDA)	T _A = 25 °C, f = 1 MHz, V _{DD} = V _{DD} (typ)	8	pF
C _I	Input pin capacitance		6	pF

Thermal Resistance

Parameter ^[5]	Description	Test Conditions	8-pin SOIC	Unit
Θ _{JA}	Thermal resistance (junction to ambient)	Test conditions follow standard test methods and procedures for measuring thermal impedance, per EIA/JESD51.	147	°C/W
Θ _{JC}	Thermal resistance (junction to case)		47	°C/W

AC Test Loads and Waveforms

Figure 12. AC Test Loads and Waveforms



AC Test Conditions

Input pulse levels10% and 90% of V_{DD}
 Input rise and fall times 10 ns
 Input and output timing reference levels0.5 × V_{DD}
 Output load capacitance 100 pF

Note

5. These parameters are guaranteed by design and are not tested.

AC Switching Characteristics

Over the [Operating Range](#)

Parameter ^[6]	Alt. Parameter	Description	Min	Max	Min	Max	Min	Max	Unit
$f_{SCL}^{[7]}$		SCL clock frequency	–	0.1	–	0.4	–	1.0	MHz
$t_{SU;STA}$		Start condition setup for repeated Start	4.7	–	0.6	–	0.25	–	μs
$t_{HD;STA}$		Start condition hold time	4.0	–	0.6	–	0.25	–	μs
t_{LOW}		Clock LOW period	4.7	–	1.3	–	0.6	–	μs
t_{HIGH}		Clock HIGH period	4.0	–	0.6	–	0.4	–	μs
$t_{SU;DAT}$	$t_{SU;DATA}$	Data in setup	250	–	100	–	100	–	ns
$t_{HD;DAT}$	$t_{HD;DATA}$	Data in hold	0	–	0	–	0	–	ns
t_{DH}		Data output hold (from SCL @ V_{IL})	0	–	0	–	0	–	ns
$t_R^{[8]}$	t_r	Input rise time	–	1000	–	300	–	300	ns
$t_F^{[8]}$	t_f	Input fall time	–	300	–	300	–	100	ns
$t_{SU;STO}$		STOP condition setup	4.0	–	0.6	–	0.25	–	μs
t_{AA}	$t_{VD;DATA}$	SCL LOW to SDA Data Out Valid	–	3	–	0.9	–	0.55	μs
t_{BUF}		Bus free before new transmission	4.7	–	1.3	–	0.5	–	μs
t_{SP}		Noise suppression time constant on SCL, SDA	–	50	–	50	–	50	ns

Figure 13. Read Bus Timing Diagram

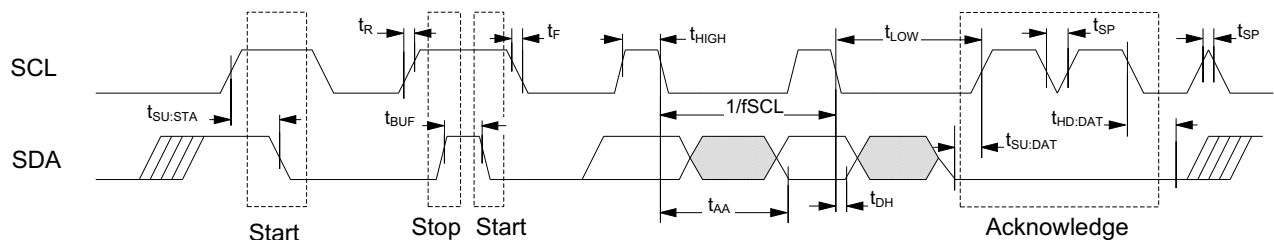
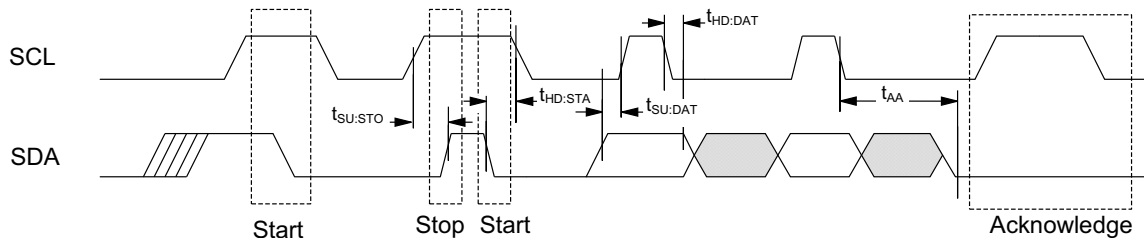


Figure 14. Write Bus Timing Diagram



Notes

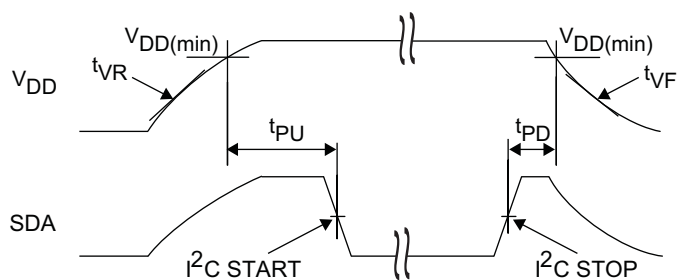
6. Test conditions assume signal transition time of 10 ns or less, timing reference levels of $V_{DD}/2$, input pulse levels of 0 to $V_{DD}(typ)$, and output loading of the specified I_{OL} and load capacitance shown in [Figure 12](#).
7. The speed-related specifications are guaranteed characteristic points along a continuous curve of operation from DC to $f_{SCL} (max)$.
8. These parameters are guaranteed by design and are not tested.

Power Cycle Timing

Over the [Operating Range](#)

Parameter	Description	Min	Max	Unit
t_{PU}	Power-up $V_{DD}(\text{min})$ to first access (START condition)	1	–	ms
t_{PD}	Last access (STOP condition) to power-down ($V_{DD}(\text{min})$)	0	–	μs
$t_{VR}^{[9, 10]}$	V_{DD} power-up ramp rate	30	–	$\mu\text{s/V}$
$t_{VF}^{[9, 10]}$	V_{DD} power-down ramp rate	30	–	$\mu\text{s/V}$

Figure 15. Power Cycle Timing



Notes

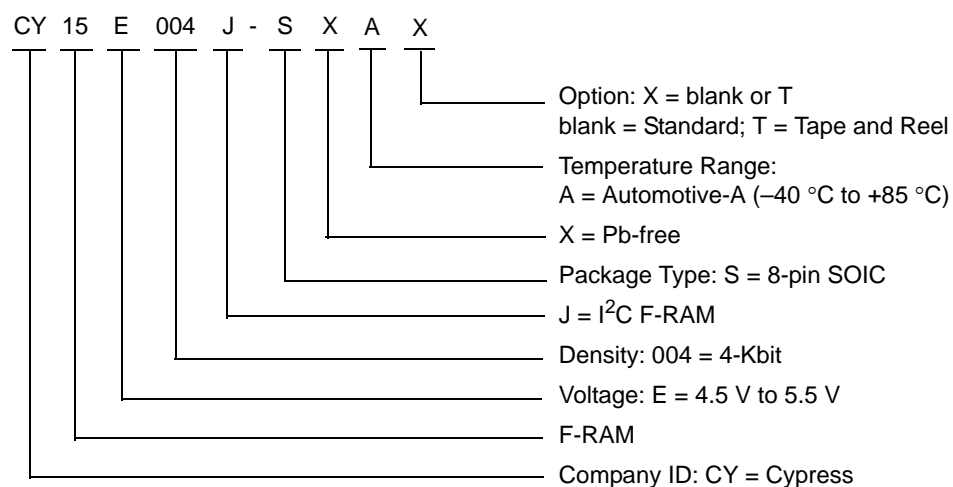
9. Slope measured at any point on the V_{DD} waveform.
10. Guaranteed by design.

Ordering Information

Ordering Code	Package Diagram	Package Type	Operating Range
CY15E004J-SXA	51-85066	8-pin SOIC	Automotive-A
CY15E004J-SXAT			

All these parts are Pb-free. Contact your local Cypress sales representative for availability of these parts.

Ordering Code Definitions

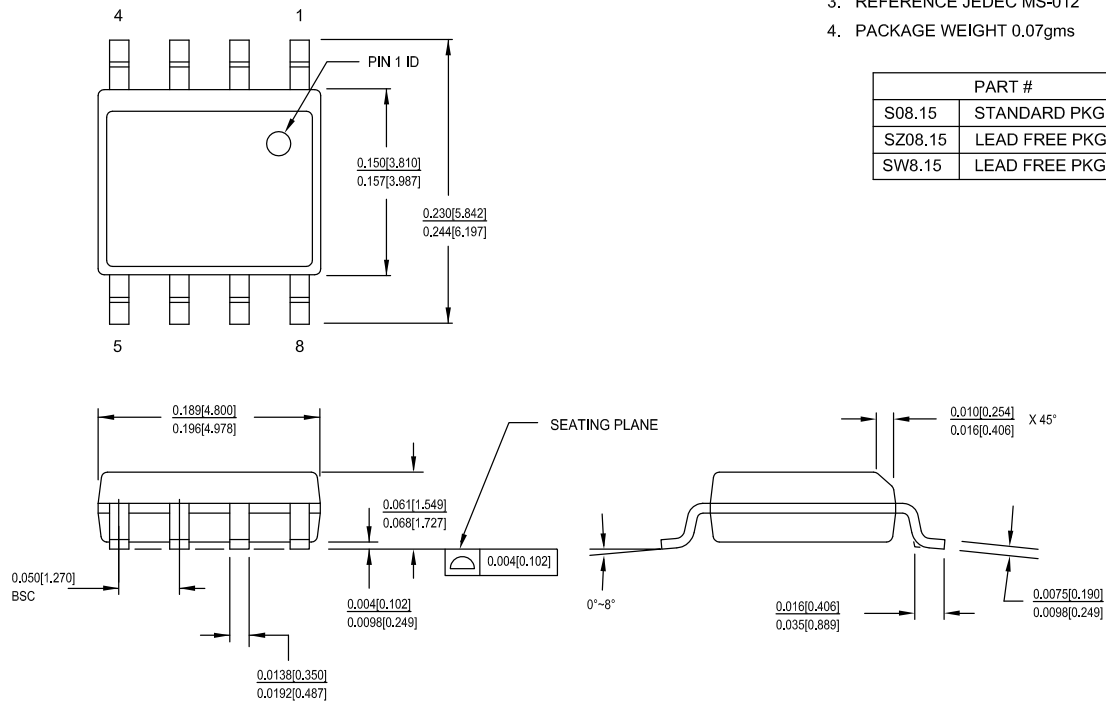


Package Diagram

Figure 16. 8-pin SOIC (150 Mils) Package Outline, 51-85066

1. DIMENSIONS IN INCHES[MM] MIN.
MAX.
2. PIN 1 ID IS OPTIONAL,
ROUND ON SINGLE LEADFRAME
RECTANGULAR ON MATRIX LEADFRAME
3. REFERENCE JEDEC MS-012
4. PACKAGE WEIGHT 0.07gms

PART #	
S08.15	STANDARD PKG
SZ08.15	LEAD FREE PKG
SW8.15	LEAD FREE PKG



51-85066 *H

Acronyms

Acronym	Description
ACK	Acknowledge
AEC	Automotive Electronics Council
CMOS	Complementary Metal Oxide Semiconductor
EIA	Electronic Industries Alliance
I ² C	Inter-Integrated Circuit
I/O	Input/Output
JEDEC	Joint Electron Devices Engineering Council
LSB	Least Significant Bit
MSB	Most Significant Bit
NACK	No Acknowledge
RoHS	Restriction of Hazardous Substances
R/W	Read/Write
SCL	Serial Clock Line
SDA	Serial Data Access
SOIC	Small Outline Integrated Circuit
WP	Write Protect

Document Conventions

Units of Measure

Symbol	Unit of Measure
°C	degree Celsius
Hz	hertz
Kb	1024 bit
kHz	kilohertz
kΩ	kilohm
MHz	megahertz
MΩ	megaohm
μA	microampere
μs	microsecond
mA	milliampere
ms	millisecond
ns	nanosecond
Ω	ohm
%	percent
pF	picofarad
V	volt
W	watt

Document History Page

Document Title: CY15E004J, 4-Kbit (512 × 8) Serial (I ² C) Automotive-A F-RAM Document Number: 002-10222				
Rev.	ECN No.	Orig. of Change	Submission Date	Description of Change
**	5039972	GVCH	12/07/2015	New data sheet.
*A	5564488	GVCH	01/23/2017	Changed status from Preliminary to Final. Updated Maximum Ratings : Updated Electrostatic Discharge Voltage: Changed "Human Body Model" from 3 kV to 2 kV. Changed "Charged Device Model" from 1.25 kV to 500 V. Removed Machine Model related information. Updated to new template.
*B	5671367	GVCH	03/24/2017	Updated Maximum Ratings : Added Note 1 and referred the same note in "Electrostatic Discharge Voltage". Updated to new template.

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